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Diodes Incorporated DMN2300UFB4-7B

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A Product Line of Diodes Incorporated



DMN2300UFB4

20V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)}	I _D T _A = +25°C (Note 5)
20V	175mΩ @ V_{GS} = 4.5V	1.30A
	240m Ω @ V _{GS} = 2.5V	1.11A
	360mΩ @ V _{GS} = 1.8V	0.91A
	500mΩ @ V _{GS} = 1.5V	0.82A

Description

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(on)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

Load switch

Features

- Footprint of just 0.6mm² thirteen times smaller than SOT23
- 0.4mm profile ideal for low profile applications
- Low Gate Threshold Voltage
- Fast Switching Speed
- ESD Protected Gate 2KV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

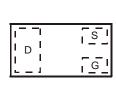
- Case: X2-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208 ④
- Weight: 0.001 grams (approximate)



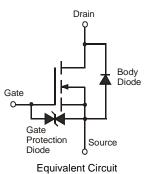


X2-DFN1006-3

Bottom View



Top View



Internal Schematic

Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DMN2300UFB4-7B	NL	7	8	10,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com.

Marking Information

DMN2300UFB4-7B



Top View Bar Denotes Gate and Source Side NL = Product Type Marking Code





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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage			V _{GSS}	±8	V
Continuous Drain Current (Note 5)	Steady State	T _A = +25°C T _A = +85°C	ID	1.30 0.96	А
Pulsed Drain Current (Note 6)			I _{DM}	6	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	500	mW
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$	R _{θJA}	250	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Turn	Мах	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	Symbol	IVIIII	Тур	IVIAX	Unit	Test Condition	
Drain-Source Breakdown Voltage	BV _{DSS}	20	_		V	V _{GS} = 0V, I _D = 10µA	
		20		1			
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	I _{DSS}				μA	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS			10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)	1	0.15	i	0.05			
Gate Threshold Voltage	V _{GS(th)}	0.45	_	0.95	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
			—	175		$V_{GS} = 4.5V, I_D = 1A$	
Static Drain-Source On-Resistance	P		—	240	mΩ	$V_{GS} = 2.5V, I_D = 750mA$	
	R _{DS (ON)}		_	360		$V_{GS} = 1.8V, I_D = 500mA$	
				500		$V_{GS} = 1.5V, I_D = 200mA$	
Forward Transfer Admittance	Y _{fs}	40	_	—	mS	$V_{DS} = 3V, I_{D} = 30mA$	
Diode Forward Voltage	V _{SD}	—	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 300mA$	
DYNAMIC CHARACTERISTICS							
Input Capacitance	Ciss	_	64.3	_	pF		
Output Capacitance	Coss	—	6.1	—	pF	V _{DS} = 25V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss	—	4.5	—	pF	1 = 1.00012	
Gate Resistance	R _g	—	70	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	—	1.6	—	nC	V _{GS} = 4.5V, V _{DS} = 15V, I _D = 1A	
Gate-Source Charge	Q _{qs}	_	0.2	_	nC		
Gate-Drain Charge	Q _{gd}	_	0.2	_	nC		
Turn-On Delay Time	t _{D(on)}	—	3.5		ns		
Turn-On Rise Time	tr	—	2.8		ns	$V_{DS} = 10V, I_{D} = 1A$	
Turn-Off Delay Time	t _{D(off)}	_	38	_	ns	$V_{GS} = 10V, R_G = 6\Omega$	
Turn-Off Fall Time	t _f	_	13	_	ns		

Notes:

Device mounted on FR-4 PCB, with minimum recommended pad layout.
Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.
Short duration pulse test used to minimize self-heating effect.



I_D, DRAIN CURRENT (A)

1.0

0.8

0.6

0.4

0.2

0.6

0.5

0.4

0.3

0.2

0.1

0

 $R_{\text{DS}(\text{ON})}$, DRAIN-SOURCE ON-RESISTANCE (Ω)

 $R_{\text{DS}(\text{ON})},$ DRAIN-SOURCE ON-RESISTANCE ($\Omega)$

Distributor of Diodes Incorporated: Excellent Integrated System Limited Datasheet of DMN2300UFB4-7B - MOSFET N-CH 20V 1.3A 3DFN Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



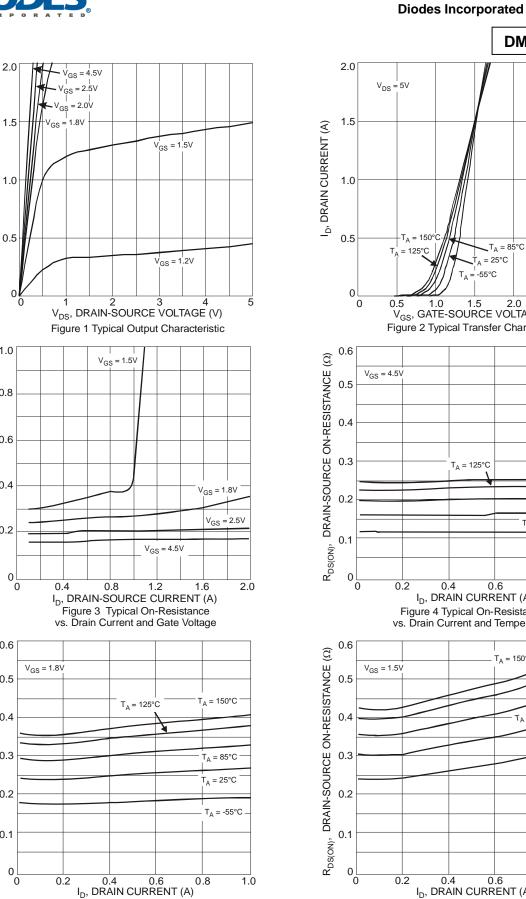
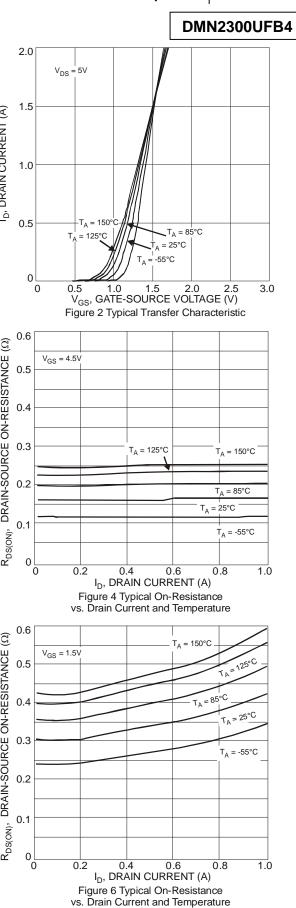


Figure 5 Typical On-Resistance vs. Drain Current and Temperature



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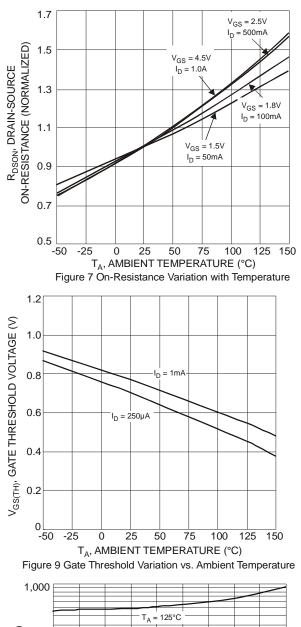
ZETEX

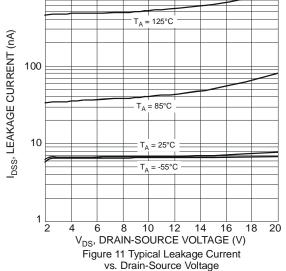
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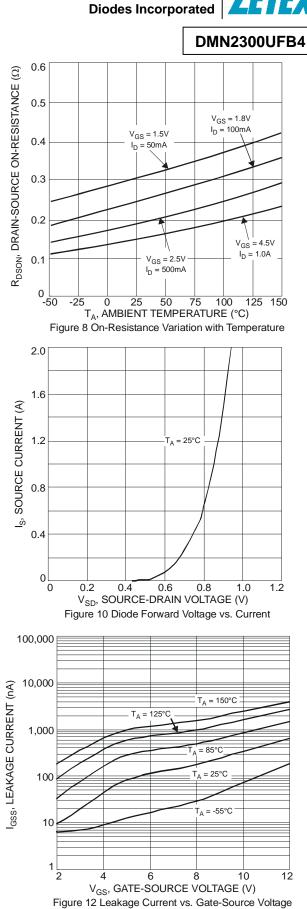




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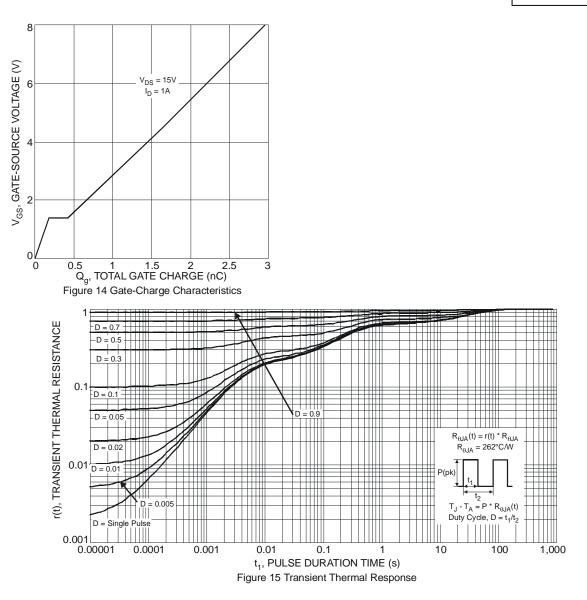
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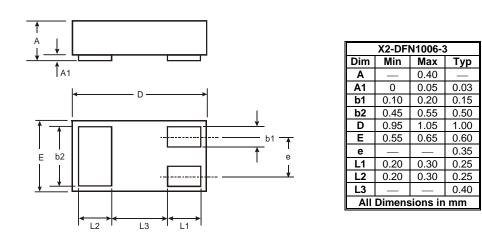


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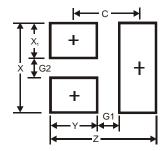
Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)				
Z	1.1				
G1	0.3				
G2	0.2				
Х	0.7				
X1	0.25				
Y	0.4				
С	0.7				







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